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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/941,595	08/30/2001	Takeo Tsukamoto	35.C15726	6437
5514	7590 05/04/2005		EXAMINER	
FITZPATRICK CELLA HARPER & SCINTO 30 ROCKEFELLER PLAZA			HODGES, MATTHEW P	
	K, NY 10112		ART UNIT	PAPER NUMBER
			2879	
			DATE MAILED: 05/04/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	09/941,595	TSUKAMOTO, TAKEO				
Office Action Summary	Examiner	Art Unit				
	Matt P. Hodges	2879				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply						
A SHORTENED STATUTORY PERIOD F THE MAILING DATE OF THIS COMMUN - Extensions of time may be available under the provision after SIX (6) MONTHS from the mailing date of this com - If the period for reply specified above is less than thirty (- If NO period for reply is specified above, the maximum - Failure to reply within the set or extended period for repl Any reply received by the Office later than three months earned patent term adjustment. See 37 CFR 1.704(b).	IICATION. s of 37 CFR 1.136(a). In no event, however, may a munication. 30) days, a reply within the statutory minimum of th tatutory period will apply and will expire SIX (6) MO y will, by statute, cause the application to become A	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) fil	ed on <u>21 March 2005</u> .					
	2b)☐ This action is non-final.					
3) Since this application is in condition	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4) Claim(s) 1-27 and 36-41 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 1-27 and 36-41 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement.						
Application Papers						
 9) The specification is objected to by the Examiner. 10) The drawing(s) filed on <u>08 March 2004</u> is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152. 						
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
Attachment(s)						
1) Notice of References Cited (PTO-892)	Summary (PTO-413)					
 Notice of Draftsperson's Patent Drawing Review (I Information Disclosure Statement(s) (PTO-1449 of Paper No(s)/Mail Date 12/6/2004. 		(s)/Mail Date. <u>04<i>200√</i></u> Informal Patent Application (PTO-152) 				

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-8, 22-25, and 36-39 are rejected under 35 U.S.C. 103(a) as being unpatentable over Xu et al. (US 5,973,444) in view of Den et al. (US 6,628,053).

Regarding claims 1-8, 22-25, 36-39, Xu discloses an electron-emitting device including carbon fibers and a catalyst of palladium for growing the carbon fibers. (Column 9 line 65 – Column 10 line 25) (Column 7 lines 52-59) (Column 5 lines 19-23). The fibers are more than 90% carbon (Column 9 lines 29-31). The fiber includes portions of the catalyst. (Column 9 lines 32-37). Here the catalyst is disposed on the substrate or alternatively on a growth surface on top of the substrate. (Column 6 lines 7-10). This growth surface can be a semiconductor or a dielectric. Further the fibers can include single wall (nanotubes), multiple-walled (nanotubes with graphenes layered in an axial direction with respect to the fiber), or vermicular fibers (nanofibers). (Column 9 lines 40-46). Xu does not appear to specify the use of Ti as the component of the oxide semiconductor growth surface, However Den in the same field of endeavor discloses the use of Titanium and Titanium Oxide as a growth structure for a carbon nanotubes. Specifically Den discloses the use of a titanium conductor (21) and titanium oxide (35) formed through oxidation on the titanium conductor. (See figure 6A). The titanium oxide is

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conductive. (Column 8 lines 5-33). The use of the semiconductor wells as a carbon nanotubes growth site advantageously controls the diameter and direction of the carbon nanotubes thus improving the device characteristics such as emitance conformity in the final product. (Column 4 lines 35-43). Thus, it would have been obvious at the time the invention was made to a person having ordinary skills in the art to the use of semiconductor Titanium Oxide as a growth structure for a carbon nanotubes as disclosed by Den into the device as taught by Xu in order to beneficially control the diameter and direction of the carbon nanotubes thus improving the device characteristics such as emitance conformity in the final product.

Claims 1, 9, 10, 13-15, 22, 26, 27, 36, 40, and 41 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamanobe et al. (US 5,847,495) in view of Xu et al. (US 5,973,444) and further in view of Den et al. (US 6,628,053).

Regarding claims 1, 9 and 10, Yamanobe discloses (see figure 1b) an electron-emitting device including a first electrode (5), second electrode (4) spaced apart from the first electrode, and a means for applying voltages to the two electrodes. The first electrode is larger than the second electrode. Further Yamanobe discloses a layer of fine conductive particles partially on the first electrode to the left of the gap (2) electrically separating the two electrodes. (Column 9 lines 1-8) (Column 10 lines 20-27). Yamanobe does not appear to specify the use of carbon nanofibers grown on Pd catalyst over an Aluminum oxide layer as the emitting film. However Xu, in the same field of endeavor, discloses the use of carbon fibers grown on a conductive cathode in the manner described in the rejection of claim 1 above in order to advantageously provide small emitter tips, increased emission uniformity, and reduced manufacturing cost (the

latter with respect to carbon fibers not grown on a catalyst as disclosed). Thus, it would have been obvious at the time the invention was made to a person having ordinary skills in the art to incorporate the use of carbon fibers grown on a conductive cathode as described by Xu into the electron emitting device as disclosed by Yamanobe in order to advantageously provide small emitter tips, increased emission uniformity, and reduced manufacturing cost.

Yamanobe in view of Xu as described above does not appear to specify the use of Ti as the component of the oxide semiconductor growth surface, However Den in the same field of endeavor discloses the use of Titanium and Titanium Oxide as a growth structure for a carbon nanotubes. Specifically Den discloses the use of a titanium conductor (21) and titanium oxide (35) formed through oxidation on the titanium conductor. (See figure 6A). The titanium oxide is stated as a conductor however its width and method of formation allow it to be partially conductive. (Column 8 lines 5-33). The use of the semiconductor wells as a carbon nanotubes growth site advantageously controls the diameter and direction of the carbon nanotubes thus improving the device characteristics such as emitance conformity in the final product. (Column 4 lines 35-43). Thus, it would have been obvious at the time the invention was made to a person having ordinary skills in the art to the use of semiconductor Titanium Oxide as a growth structure for a carbon nanotubes as disclosed by Den into the device as taught by Yamanobe in view of Xu in order to beneficially control the diameter and direction of the carbon nanotubes thus improving the device characteristics such as emitance conformity in the final product.

The recitation of a higher voltage on the second electrode than applied to the first electrode has not been given patentable weight because is considered an intended used recitation. It has been held that a recitation with respect to the manner in which a claimed apparatus is

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intended to be employed does not differentiate the claimed apparatus from a prior art apparatus satisfying the claimed structural limitations.

Regarding claims 13-15, 22, 26-27, 36, 40, and 41, Yamanobe further discloses the use of the aforementioned electron-emitting devices in a display device (see figure 58). Here the display further comprises an anode (115) and a phosphor film (114) formed on the anode. (Column 55 lines 59-67).

Claims 11, 12, 16-21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamanobe et al. (US 5,847,495) in view of Xu et al. (US 5,973,444) in view of Den et al. (US 6,628,053) and further in view of Yoshioka et al. (5,066,883).

Regarding claims 11 and 12, Yamanobe further discloses (see figure 35ac) the alternative use of a step portion 21 under the first electrode to raise the electrode higher than the second electrode. (Column 48 lines 1-9). Yamanobe does not appear to disclose the step portion being integral with the substrate however Yoshioka, in the same field of endeavor, discloses (see figure 7) the use of directing etching the substrate in order to create the step portion and raise the first electrode. (Column 5 lines 54-59). This direct etching advantageously eliminates the need for several manufacturing steps and thus decreases manufacturing cost. Thus, it would have been obvious at the time the invention was made to a person having ordinary skills in the art to incorporate the step portion being integral with the substrate as described by Yoshioka into the electron emitting device as disclosed by Yamanobe in view of Xu and further in view of Den in order to advantageously eliminates the need for several manufacturing steps and thus decreases manufacturing cost.

Regarding claims 16-18, the ends of the plurality of fibers are higher off of the substrate than the second electrode.

Regarding claims 20 and 21, Yamanobe further discloses the use of the aforementioned electron-emitting devices in a display device (see figure 58). Here the display further comprises an anode (115) and a phosphor film (114) formed on the anode. (Column 55 lines 59-67). Each electron-emitting portion is independently addressable thus forming an image display device.

Regarding claim 19, Yamanobe in view of Xu in view of Den and further in view of Yoshioka discloses all the claimed elements but does not appear to specify the use of a first electrode that is larger in thickness than the second electrode while also having the ends of the fibers arranged above the second electrode. However the use of a larger electrode in combination with the substrate step portions allows for smaller etchings in the substrate while still allowing for the same overall first electrode height. The ability to have smaller surface etchings in the substrate advantageously allows for a greater ease of manufacture. Thus, it would have been obvious at the time the invention was made to a person having ordinary skills in the art to incorporate larger electrode into the electron emitting device as disclosed by Yamanobe in view of Xu in view of Den and further in view of Yoshioka in order to advantageously allow for a greater ease of manufacture.

Response to Arguments

Applicant's arguments filed 3/21/2005 have been fully considered but they are not persuasive.

Regarding applicant's assertion that the layer 35 of figure 6A in Den ('053) is not semiconductive, the examiner respectfully disagrees. Given the very thin width of the layer and the tunneling properties of the layer, in addition to the operational requirement of charge transfer to the fiber (24) it is the decision of the examiner that the layer in question is in fact semiconductive.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Contact Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matt P Hodges whose telephone number is (571) 272-2454. The examiner can normally be reached on 7:30 AM to 4:00 PM M-F.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nimesh Patel can be reached on (571) 272-2457. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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